



Product brief

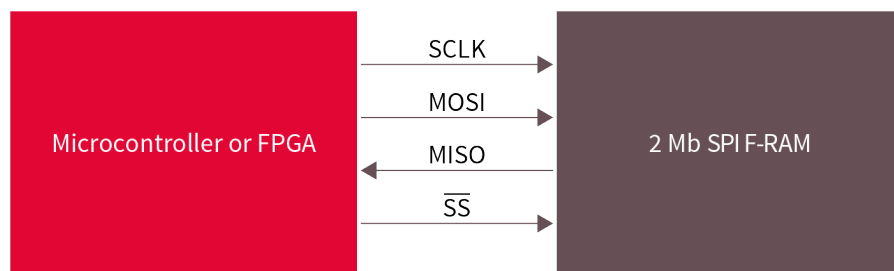
HiRel RadHard non-volatile SPI F-RAM

Infineon's HiRel memories perform in extreme environments

Infineon offers the industry's first radiation hardened, highly reliable, small footprint, 2 Mb non-volatile Serial Peripheral Interface (SPI) Ferroelectric RAM (F-RAM). The industry standard Serial Peripheral Interface (SPI) is simple to use with broad ecosystem support and the F-RAM supports a 16-pin ceramic SOP package. Our radiation hardened SPI F-RAM memory is ideal for data storage for sensors and instruments, data logging for calibration data for satellites and processor boot code applications.

Our RadHard SPI F-RAM's virtually infinite endurance, instant non-volatile write technology, greater than 100-year data retention and immune to Single Event Upsets (SEU) is the highest reliable, non-volatile memory for space applications and is a direct replacement for serial flash and EEPROMs.

Datalogger for satellite calibration data



Key benefits

Ultimate reliability

- > DLAM QML-V
- > QCI, datapacks
- > RHA, WLAT

Product features

- > 2 Mb densities
- > 25 MHz SPI data interface
- > TID > 150 Krad (Si)
- > SEL > 114 MeV.cm²/mg
- > SEFI < 1.34 x 10⁻⁴ err/dev.day
- > SEU immune
- > Mil temperature grade
- > 16-pin ceramic SOP
- > DLAM QML-V certified

Key applications

- > Data logging for calibration data for satellites
- > Data storage for sensors and instruments

Differentiated memory portfolio

- > Performance
- > Density
- > Reliability
- > Longevity

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Radiation hardened memories

Infineon's HiRel RadHard memory products portfolio consists of the world's most-reliable non-volatile memory and offers a wide selection of NOR flash, F-RAM, and SRAM solutions that enhance overall system computing limits, while providing Size, Weight and Power (SWaP) benefits with greater design flexibility to satisfy the needs of today's advanced space systems and beyond.

Key features

CYRS15B102Q

- › 2 Mb density
- › SPI interface operating up to 25 MHz
- › Infineon instant non-volatile write technology
- › 10-trillion read/write cycle endurance
- › 120 years data retention at +85°C
- › 2.0–3.6 V operating voltage range
- › Low operating current (10 mA max)
- › –55°C to +125°C military temperature grade
- › 16-pin ceramic SOP
- › DLAM QML-V qualified
- › Radiation performance
 - TID: > 150 Krad (Si)
 - SEL: > 114 MeV.cm²/mg [LET] @ 115°C
 - SEU: immune
 - SEFI: < 1.34 x 10⁻⁴ err/dev.day

Support: www.infineon.com/hirelmemory

Parts list

Density	Description	Infineon P/N	Operating temp	Qual. Level	TID ¹⁾	SEL ²⁾	SEU ³⁾	SEFI ⁴⁾
2 Mb	SPI F-RAM	CYRS15B102Q-GGMB	–55°C to 125°C	QML-V	150 Krad (Si)	> 114	Immune	< 1.34 x 10 ⁻⁴
		CYPT15B102Q-GGMB	–55°C to 125°C	PROTOTYPE	–	–	–	–
		5962R1821601VX	–55°C to 125°C	DLAM QML-V	150 Krad (Si)	> 114	Immune	–

1) Total Ionizing Dose [Krad (Si)]

2) Single Event Latchup MeV.cm²/mg [LET] @ 115°C

3) Single Event Upset

4) Single Event Functional Interrupt err/device-day



www.infineon.com

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